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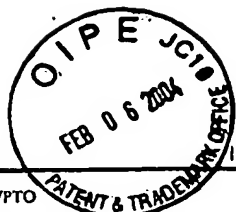
Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known				
				Application Number		New Patent Application		
				Filing Date		August 19, 2003		
				First Named Inventor		Taiji NODA		
				Group Art Unit		2814		
				Examiner Name		H. Weiss		
				Attorney Docket Number		740819-1027		
Sheet	1	of	1					
U.S. PATENT DOCUMENTS								
Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		Number	Kind Code ² (if known)					
		US-6,087,209		Yeap et al.	07/11/2000			
		US-6,078,081		Lee	06/20/2000			
		US-6,030,863		Chang et al.	02/29/2000			
		US-6,013,546		Gardner et al.	01/11/2000			
		US-5,602,045		Kimura	02/11/1997			
FOREIGN PATENT DOCUMENTS								
Examiner Initials ¹	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁴
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
		Japan	11-40801		Hideki	02/12/1999		Abstract
		Japan	03-174721		Masataka et al.	07/29/1991		Abstract
		Japan	62-200723		Tadashi	09/04/1987		Abstract
OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS								
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		M.C. Ozturk et al., "Very shallow p ⁺ -n junction formation by low-energy BF ₃ ⁺ ion implantation into crystalline and germanium preamorphized silicon", Appl. Phys. Lett. 52 (12), pp. 963-965, March 1988.						
EXAMINER SIGNATURE AND DATE								
Examiner Signature					Date Considered	8/22/04		

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete if Known	
				Application Number	10/642,655
				Filing Date	August 19, 2003
				First Named Inventor	Taiji NODA
				Art Unit	2811
				Examiner Name	Eddie C. H. Lee
Sheet	1	of	1	Attorney Docket Number	740819-1027

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	U.S. Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)			
		US-			
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ⁴ Number ⁵ Kind (if)				
		JP 2000-260728	09-22-2000	Tsuji et al.		Abstract and Partial Translation

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